

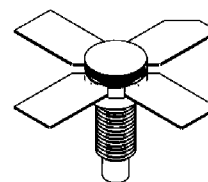
## The RF Line UHF Linear Power Transistor

Designed for 4.0 watt stages in Band V TV transposer amplifiers. Gold metallized dice and diffused emitter ballast resistors are used to enhance reliability, ruggedness and linearity.

- Band IV and V (470–860 MHz)
- 4.0 W —  $P_{ref}$  @ -60 dB IMD
- 25 V —  $V_{CC}$
- High Gain — 7.0 dB Min, Class A @  $f = 860$  MHz
- Gold Metallization for Reliability

# TPV598

4.0 W, 470–860 MHz  
UHF LINEAR  
POWER TRANSISTOR



CASE 244-04,

### MAXIMUM RATINGS

| Rating                         | Symbol    | Value       | Unit |
|--------------------------------|-----------|-------------|------|
| Collector–Emitter Voltage      | $V_{CEO}$ | 27          | Vdc  |
| Collector–Base Voltage         | $V_{CBO}$ | 45          | Vdc  |
| Emitter–Base Voltage           | $V_{EBO}$ | 4.0         | Vdc  |
| Operating Junction Temperature | $T_J$     | 200         | °C   |
| Storage Temperature Range      | $T_{stg}$ | -65 to +200 | °C   |

### THERMAL CHARACTERISTICS

| Characteristic  | Symbol          | Max     | Unit |
|---|-----------------|---------|------|
| Thermal Resistance, Junction to Case ( $T_C = 70^\circ\text{C}$ ) | $R_{\theta JC}$ | 6.2     | °C/W |
| Thermal Resistance, Case to Heatsink                              | $R_{\theta CH}$ | 0.4 Typ | °C/W |

### ELECTRICAL CHARACTERISTICS

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

### OFF CHARACTERISTICS

|  |               |     |   |     |     |
|--|---------------|-----|---|-----|-----|
| Collector–Emitter Breakdown Voltage ( $I_C = 60$ mA, $I_B = 0$ ) | $V_{(BR)CEO}$ | 27  | — | —   | Vdc |
| Collector–Base Breakdown Voltage ( $I_C = 10$ mA, $I_E = 0$ )    | $V_{(BR)CBO}$ | 45  | — | —   | Vdc |
| Emitter–Base Breakdown Voltage ( $I_E = 3.0$ mA, $I_C = 0$ )     | $V_{(BR)EBO}$ | 4.0 | — | —   | Vdc |
| Collector–Emitter Leakage Current ( $V_{CE} = 20$ V)             | $I_{CEO}$     | —   | — | 5.0 | mA  |

### ON CHARACTERISTICS

|  |          |    |   |   |   |
|--|----------|----|---|---|---|
| DC Current Gain ( $I_C = 500$ mA, $V_{CE} = 20$ V) | $h_{FE}$ | 10 | — | — | — |
|--|----------|----|---|---|---|

### DYNAMIC CHARACTERISTICS

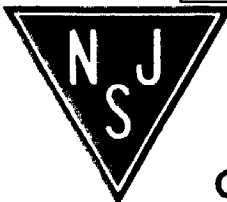
|  |          |   |   |    |    |
|--|----------|---|---|----|----|
| Output Capacitance ( $V_{CB} = 25$ V, $I_E = 0$ , $f = 1.0$ MHz) | $C_{ob}$ | — | — | 20 | pF |
|--|----------|---|---|----|----|

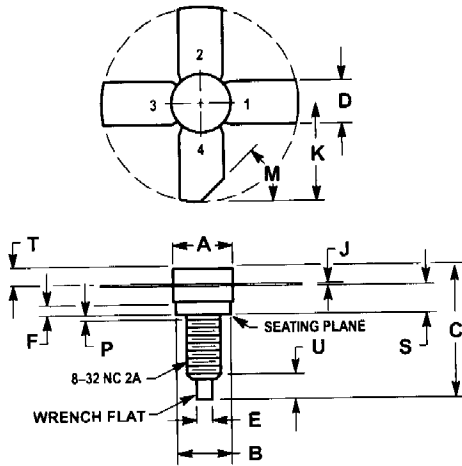
### FUNCTIONAL TESTS

|  |          |     |     |     |     |
|--|----------|-----|-----|-----|-----|
| Common–Emitter Amplifier Power Gain<br>( $V_{CE} = 25$ V, $P_{out} = 4.0$ W, $f = 860$ MHz, $I_C = 850$ mA)  | $G_{PE}$ | 7.0 | —   | —   | dB  |
| Intermodulation Distortion, 3 Tone<br>( $f = 860$ MHz, $V_{CE} = 25$ V, $I_E = 850$ mA, $P_{ref} = 4.0$ W,<br>Vision Carrier = -8.0 dB, Sound Carrier = -7.0 dB,<br>Sideband Signal = -16 dB, Specification TV05001) | $IMD_1$  | —   | —   | -58 | dB  |
| Cutoff Frequency<br>( $V_{CE} = 25$ V, $I_C = 850$ mA)   | $f_t$    | —   | 2.0 | —   | GHz |

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

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| DIM | MILLIMETERS |       | INCHES  |       |
|-----|-------------|-------|---------|-------|
|     | MIN         | MAX   | MIN     | MAX   |
| A   | 7.06        | 7.26  | 0.278   | 0.286 |
| B   | 6.20        | 6.50  | 0.244   | 0.256 |
| C   | 14.99       | 16.51 | 0.590   | 0.650 |
| D   | 5.46        | 5.96  | 0.215   | 0.235 |
| E   | 1.40        | 1.65  | 0.055   | 0.065 |
| G   | 1.52        | —     | 0.060   | —     |
| J   | 0.08        | 0.17  | 0.003   | 0.007 |
| K   | 11.05       | —     | 0.435   | —     |
| M   | 45° NOM     |       | 45° NOM |       |
| P   | —           | 1.27  | —       | 0.050 |
| S   | 3.00        | 3.25  | 0.118   | 0.128 |
| T   | 1.40        | 1.77  | 0.055   | 0.070 |
| U   | 2.92        | 3.68  | 0.115   | 0.145 |

STYLE 1:  
 PIN 1. EMITTER  
 2. BASE  
 3. EMITTER  
 4. COLLECTOR